



A Product Line of Diodes Incorporated



DXT2014P5

140V PNP MEDIUM POWER TRANSISTOR PowerDI[®]5

Features

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 3.2W
- V_{CEO} = -140V
- I_C = -4A; I_{CM} = -10A
- Low Saturation voltage
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Features

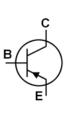
SLIC DC-DC converter

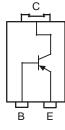
Mechanical Data

- Case: PowerDI[®]5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.093 grams (approximate)









Top View

Bottom View

Device Schematic

Pin-out diagram

Ordering Information (Note 3)

Part Number	Case	Packaging
DXT2014P5-13	PowerDI [®] 5	5000/Tape & Reel

Notes: 1. No purposefully added lead. Halogen and Antimony Free.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



DXT2014 = Product Type Marking Code D'I'= Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 09 for 2009) WW = Week code (01 to 53)





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-180	V
Collector-Emitter Voltage	V _{CEO}	-140	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	lc	-4	А
Peak Pulse Current	I _{CM}	-10	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 4)	PD	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 4) @T _A = 25°C	$R_{ heta JA}$	39	°C/W
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 5)	PD	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 5) $@T_A = 25^{\circ}C$	$R_{ ext{ heta}JA}$	75	°C/W
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 6)	PD	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 6) $@T_A = 25^{\circ}C$	$R_{ heta JA}$	169	°C/W
Thermal Resistance, Junction to Collector Terminal	$R_{ extsf{ heta}JT}$	5.6	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 4. Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.

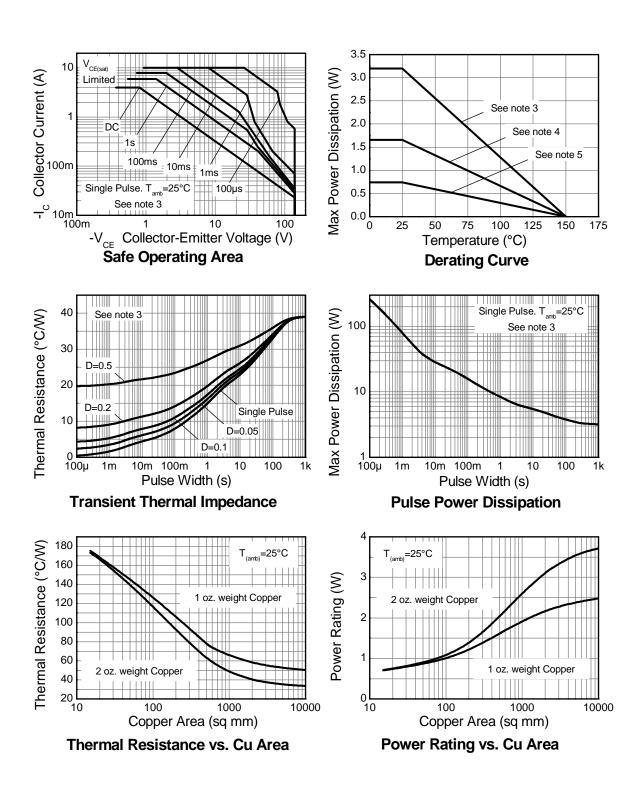
5. Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.

6. Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.













Electrical Characteristics @T_A = 25°C unless otherwise specified

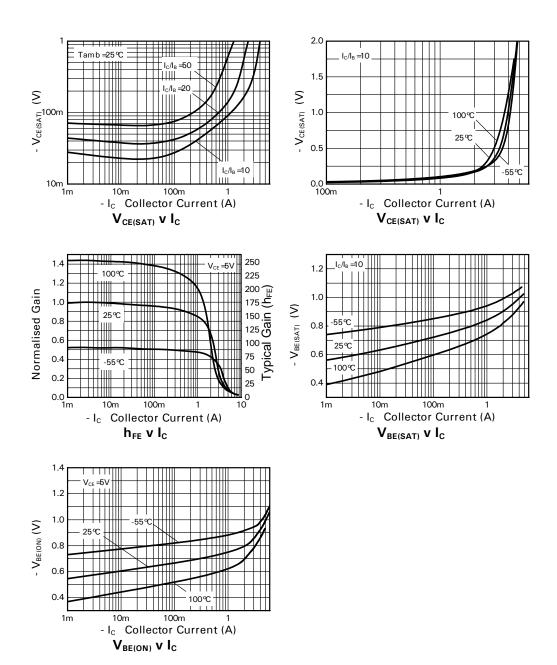
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-180	-200	_	V	$I_{\rm C} = -100 \mu {\rm A}$
Collector-Emitter Breakdown Voltage (Note 7)	V _{(BR)CEO}	-140	-160	_	V	$I_{\rm C} = -10 \mathrm{mA}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7.0	-8.0	_	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	_	<1 —	-20 -0.5	nA μA	V _{CB} = -150V V _{CB} = -150V, T _{amb} = 100 °C
Collector Cutoff Current	I _{CER} R≤1kΩ	_	<1	-20 -0.5	nA μA	V _{CB} = -150V V _{CB} = -150V, T _{amb} = 100 °C
Emitter Cutoff Current	I _{EBO}	_	<1	-10	nA	$V_{EB} = -6V$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	-40 -55 -85 -275	-60 -80 -120 -360	mV	I _C = -0.1A, I _B = -5mA I _C = -0.5A, I _B = -50mA I _C = -1A, I _B = -100mA I _C = -3A, I _B = -300mA
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	_	-940	-1040	mV	I _C = -3A, I _B = -300mA
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	_	-830	-930	mV	$V_{CE} = -5V, I_{C} = -3A$
DC Current Gain (Note 7)	h _{FE}	100 100 45 —	225 200 100 5	300 —		$V_{CE} = -5V, I_C = -10mA$ $V_{CE} = -5V, I_C = -1A$ $V_{CE} = -5V, I_C = -3A$ $V_{CE} = -5V, I_C = -10A$
Transition Frequency	f _T	_	120	_	MHz	$V_{CE} = -10V, I_C = -100mA,$ f = 50MHz
Output Capacitance	C _{obo}		33		pF	V _{CB} = -10V, f = 1MHz
Switching Times	t _{on} t _{off}		42 636		ns ns	$V_{CC} = -50V$, $I_C = 1A$, $I_{B1} = -I_{B2} = -100mA$

Notes: 7. Pulse Test: Pulse width \leq 300µs. Duty cycle \leq 2.0%.





Typical Characteristic

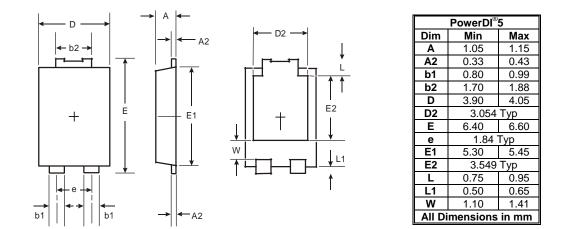




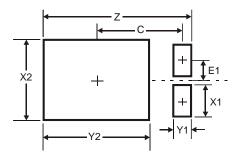




Package Outline Dimensions



Suggested Pad Layout



-	
Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
С	3.87
E1	0.9





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